Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

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BC182, BC182A, BC182B

Amplifier Transistors

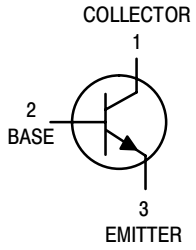
NPN Silicon

ON Semiconductor®

http://onsemi.com

Features

- Pb−Free Packages are Available*



MAXIMUM RATINGS

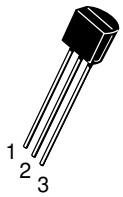
Rating	Symbol	BC182	Unit
Collector−Emitter Voltage	V_{CEO}	50	Vdc
Collector−Base Voltage	V_{CBO}	60	Vdc
Emitter−Base Voltage	V_{EBO}	6.0	Vdc
Collector Current − Continuous	I_C	100	mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	350 2.8	mW mW/°C
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	1.0 8.0	W mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	−55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

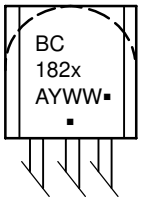
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	125	°C/W

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



TO−92
CASE 29
STYLE 17

MARKING DIAGRAM



BC182x = Device Code
x = A or B
A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
BC182	TO−92	5000 Units / Box
BC182G	TO−92 (Pb−Free)	5000 Units / Box
BC182A	TO−92	5000 Units / Box
BC182AG	TO−92 (Pb−Free)	5000 Units / Box
BC182B	TO−92	5000 Units / Box
BC182BG	TO−92 (Pb−Free)	5000 Units / Box
BC182BRL1	TO−92	2000 / Tape & Reel
BC182BRL1G	TO−92 (Pb−Free)	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I_C = 2.0 mA, I_B = 0)		$V_{(BR)CEO}$	50	–	–	V
Collector – Base Breakdown Voltage (I_C = 10 μA, I_E = 0)		$V_{(BR)CBO}$	60	–	–	V
Emitter – Base Breakdown Voltage (I_E = 100 μA, I_C = 0)		$V_{(BR)EBO}$	6.0	–	–	V
Collector Cutoff Current (V_{CB} = 50 V, V_{BE} = 0)		I_{CBO}	–	0.2	15	nA
Emitter–Base Leakage Current (V_{EB} = 4.0 V, I_C = 0)		I_{EBO}	–	–	15	nA
ON CHARACTERISTICS						
DC Current Gain		h_{FE}				–
(I_C = 10 μA, V_{CE} = 5.0 V)	BC182		40	–	–	
(I_C = 2.0 mA, V_{CE} = 5.0 V)	BC182		120	–	500	
	BC182A		120		220	
	BC182B		180	–	500	
(I_C = 100 mA, V_{CE} = 5.0 V)	BC182		80		–	
Collector – Emitter On Voltage		$V_{CE(sat)}$				V
(I_C = 10 mA, I_B = 0.5 mA)			–	0.07	0.25	
(I_C = 100 mA, I_B = 5.0 mA) (Note 1)			–	0.2	0.6	
Base – Emitter Saturation Voltage (I_C = 100 mA, I_B = 5.0 mA) (Note 1)		$V_{BE(sat)}$	–	–	1.2	V
Base–Emitter On Voltage		$V_{BE(on)}$				V
(I_C = 100 μA, V_{CE} = 5.0 V)			–	0.5	–	
(I_C = 2.0 mA, V_{CE} = 5.0 V)			0.55	0.62	0.7	
(I_C = 100 mA, V_{CE} = 5.0 V) (Note 1)			–	0.83	–	
DYNAMIC CHARACTERISTICS						
Current – Gain — Bandwidth Product		f_T				MHz
(I_C = 0.5 mA, V_{CE} = 3.0 V, f = 100 MHz)			–	100	–	
(I_C = 10 mA, V_{CE} = 5.0 V, f = 100 MHz)			150	200	–	
Common Base Output Capacitance (V_{CB} = 10 V, I_C = 0, f = 1.0 MHz)		C_{ob}	–	–	5.0	pF
Common Base Input Capacitance (V_{EB} = 0.5 V, I_C = 0, f = 1.0 MHz)		C_{ib}	–	8.0	–	pF
Small–Signal Current Gain		h_{fe}				–
(I_C = 2.0 mA, V_{CE} = 5.0 V, f = 1.0 kHz)	BC182		125	–	500	
	BC182A		125	–	260	
	BC182B		240	–	500	
Noise Figure (I_C = 0.2 mA, V_{CE} = 5.0 V, R_S = 2.0 kΩ, f = 1.0 kHz)		NF	–	2.0	10	dB

1. Pulse Test: Tp 300 s, Duty Cycle 2.0%.

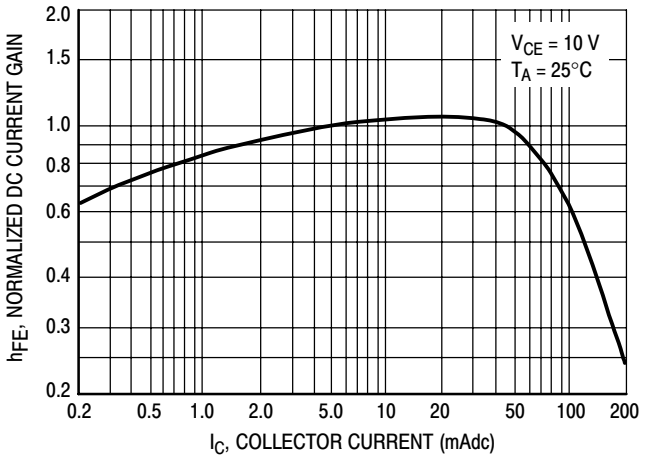


Figure 1. Normalized DC Current Gain

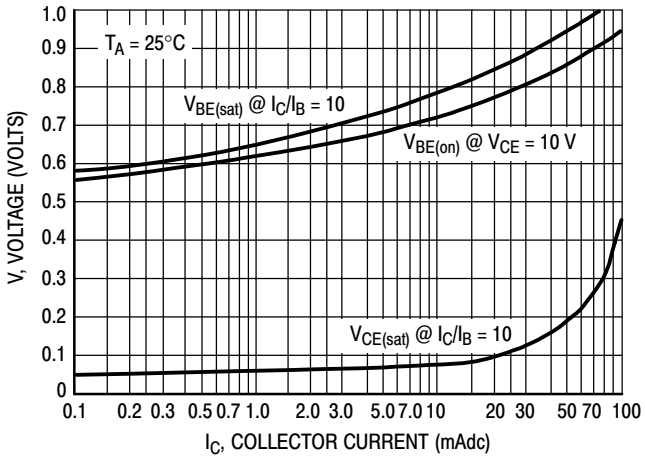


Figure 1. "Saturation" and "On" Voltages

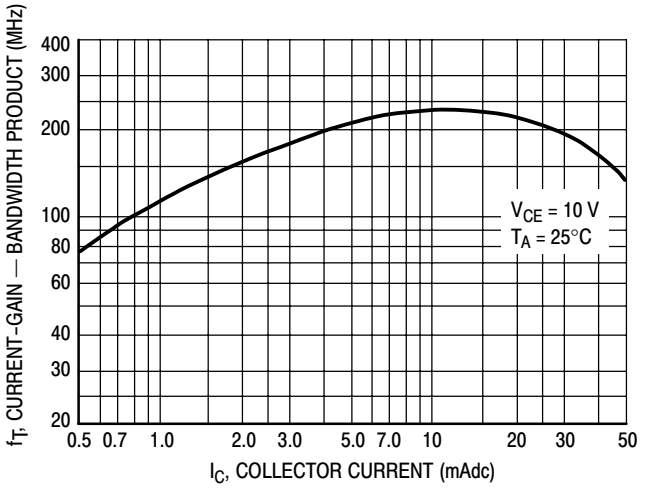


Figure 2. Current−Gain — Bandwidth Product

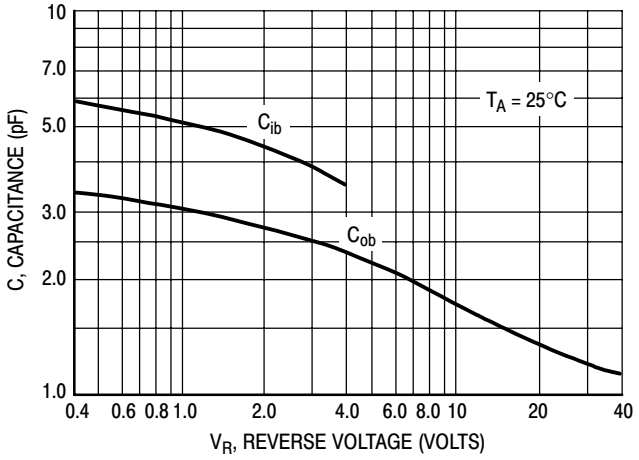


Figure 3. Capacitances

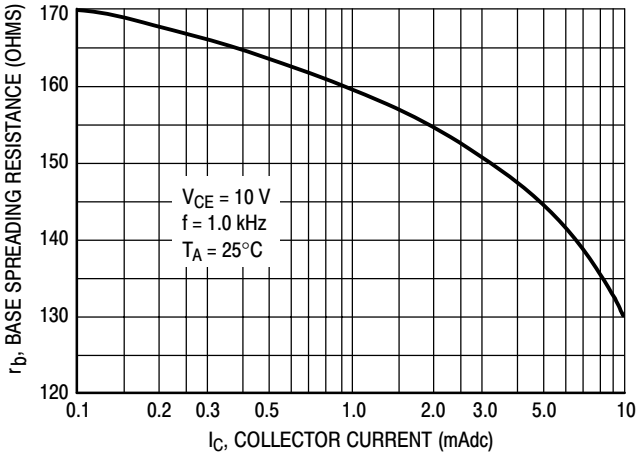
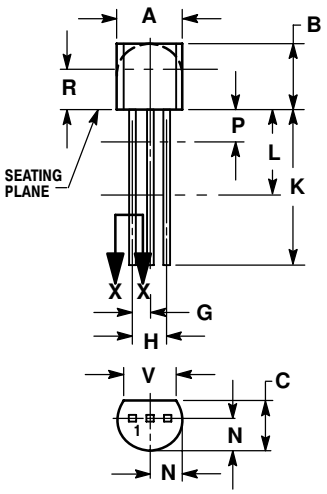
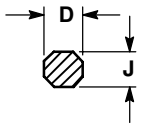


Figure 4. Base Spreading Resistance

PACKAGE DIMENSIONS

TO–92
TO–226AA
CASE 29–11
ISSUE AL





SECTION X–X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

PUBLICATION ORDERING INFORMATION

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